

OPTOELECTRONIC DEVICES & MODULES

LIGHT EMITTING DIODE

TYPE	DESCRIPTION	MAXIMUM RATING			ELECTRO-OPTICAL CHARACTERISTIC							NOTE	PKG
		PD [mW]	IF [mA]	VR [V]	λ_p [nm]	Vf Typ. [V]	IF [mA]	θ_e Typ. [deg]	Q Typ. [deg]				
NJL1104B	GaAs Infrared LED	150	100	6	940	1.2	50	2.8	50	30	High input current type.	A A A	
NJL1110B		150	100	6	940	1.2	50	1.7	50	20			
NJL1112B		225	150	6	940	1.3	100	3.5	50	20			
NJL1120B	GaAlAs Infrared LED	170	100	6	900	1.3	50	4.9	50	20	Ø 4mm narrow beam. Flat glass.	A A A A C	
NJL1121B		170	100	6	900	1.3	50	6.5	50	15			
NJL1122B		170	100	6	900	1.3	50	7	50	10			
NJL1120F		170	100	6	900	1.3	50	4.9	50	70			
NJL1121F		170	100	6	900	1.3	50	6.5	50	70			

PHOTO DIODE

TYPE	DESCRIPTION	MAXIMUM RATING			ELECTRO-OPTICAL CHARACTERISTIC						NOTE	PKG
		PD [mW]	IF [mA]	VR [V]	λ_p [nm]	IL Type. [µA]	Ee [mW/cm²]	IL Max. [nA]	ID Max. VR [V]	θ Typ. [deg]		
NJL6103B	PIN Photo Diode	150	100	15	920	20	2	1.0	1	25		A A A
NJL611B		150	100	15	850	10	2	1.0	1	20		
NJL612B		150	100	15	850	30	2	1.0	1	25		

PHOTO TRANSISTOR

TYPE	DESCRIPTION	MAXIMUM RATING			ELECTRO-OPTICAL CHARACTERISTIC						NOTE	PKG
		Pc [mW]	VCEO [V]	IC [mA]	λ_p [nm]	IL Type. [mA]	VCE [V]	Ee [mW/cm²]	ICEO Max. [nA]	VCE [V]		
NJL7112B	Photo Transistor	150	40	50	900	12	10	2	100	30		B B B B
NJL7113B		150	25	20	900	4	10	0.5	100	20		
NJL721B		150	40	50	740	2.5	10	2	100	30		
NJL722B		150	8	50	740	5	10	2	200	30		
NJL7260B	Photo Darlington Transistor	150	25	100	740	12.5	10	0.2	100	6		B
NJL811B	Photo Diode with Current Amplifier	150	40	50	900	4	10	2	100	6		B

PHOTO IC

TYPE	DESCRIPTION	MAXIMUM RATING			ELECTRO-OPTICAL CHARACTERISTIC						NOTE	PKG
		P tot [mW]	V cc [V]	I OL [mA]	V OL Max. [V]	EeHL Typ. [µW/cm²]	E eHL Typ. [µW/cm²]	tp HL Typ. [µS]	tp LH Typ. [µS]	tr,tf Typ. [µS]		
NJL3227B	Open Collector	150	16	50	0.4	150	75	1	2	0.1	Active Low. Active High.	B B B
NJL3228B	Digital Output	150	16	50	0.4	75	150	2	1	0.1		
NJL3229B	Digital Output	150	16	50	0.4	50	60	10	10	0.1		

PHOTO COUPLER

TYPE	DESCRIPTION	MAXIMUM RATING			ELECTRO-OPTICAL CHARACTERISTIC						NOTE	PKG
		P tot [mW]	IF [mA]	VCEO [V]	CTR Min. [%]	CTR Max. [%]	IF [mA]	ICEO Max. [nA]	V IO [Vrms]	AC1min		
NJL5121D*	Transistor Output	250	70	35	30	300	10	50	6	4000		E E
NJL5125D*	Darlington Transistor Output	200	70	35	300	-	1	100	5	4000		
NJL5126D*	AC Input	300	±70	35	100	600	10	100	5	4000		E
NJL5151D*	Small package Transistor Output	200	70	35	40	480	5	100	10	4000	2 channel type 2 channel type 3 channel type 3 channel type High VCE type High VCE type High VCE type High VCE type High VCE type High input current type.	F I G J H K F I F I I
NJL5151M*		200	70	35	40	480	5	100	10	4000		
NJL5152D*		150/CH.	50	35	40	480	5	100	10	4000		
NJL5152M*		150/CH.	50	35	40	480	5	100	10	4000		
NJL5153D*		150/CH.	50	35	40	480	5	100	10	4000		
NJL5153M*		150/CH.	50	35	40	480	5	100	10	4000		
NJL5154D*		200	70	70	40	480	5	100	10	4000		
NJL5154M*		200	70	70	40	480	5	100	10	4000		
NJL5155D*		200	70	120	40	480	5	100	10	4000		
NJL5155M*		200	70	120	40	480	5	100	10	4000		
NJL5156M*		200	150	35	40	480	5	100	10	2		

*UL Recognized.

TYPE	DESCRIPTION	P tot [mW]	IF [mA]	Vcc [V]	VOL Max. [V]	I FHL Typ. [mA]	I FLH Typ. [mA]	tp HL Typ. [µS]	tp LH Typ. [µS]	V IO [Vrms]	NOTE	PKG
		AC1min										
NJL5127D	Open Collector	170	50	16	0.4	1.1	0.8	1	2	3500	Active Low	E
NJL5128D	Digital Output	170	50	16	0.4	0.8	1.1	2	1	3500	Active High	E
NJL5131D	Digital Output	170	50	16	0.4	0.85	0.45	0.3	1	3500	Active Low	E

PACKAGE OUTLINE

